

Datasheet

N-channel 600 V, 1.3 Ω typ., 3.5 A, MDmesh[™] M2 Power MOSFETs in DPAK, TO-220 and IPAK packages

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Product status links
STD5N60M2
STP5N60M2
STU5N60M2

Features

Order code	V _{DS} @ T _{Jmax}	R _{DS(on)} max.	I _D
STD5N60M2			
STP5N60M2	650 V	1.4 Ω	3.5 A
STU5N60M2			

Extremely low gate charge

- Excellent output capacitance (COSS) profile
- 100% avalanche tested
- Zener-protected

Applications

Switching applications

Description

These devices are N-channel Power MOSFETs developed using the MDmesh[™] M2 technology. Thanks to their strip layout and improved vertical structure, these devices exhibit low on-resistance and optimized switching characteristics, rendering them suitable for the most demanding high-efficiency converters.



1 Electrical ratings

Table 1.	Absolute	maximum	ratings
----------	----------	---------	---------

Symbol	Parameter	Value	Unit
V _{GS}	Gate-source voltage	±25	V
1-	Drain current (continuous) at T _C = 25 °C	3.5	
ID	Drain current (continuous) at T _C = 100 °C	2.2	A
I _{DM} ⁽¹⁾	Drain current (pulsed)	14	Α
P _{TOT}	Total dissipation at T_C = 25 °C	45	W
dv/dt ⁽²⁾	Peak diode recovery voltage slope	15	V/ns
dv/dt ⁽³⁾	MOSFET dv/dt ruggedness	50	v/ns
T _{stg}	Storage temperature range	-55 to 150	3°
Tj	Operating junction temperature range	-55 10 150	

1. Pulse width limited by safe operating area.

2. $I_{SD} \leq 3.5 \text{ A}$, di/dt $\leq 400 \text{ A}/\mu s$; V_{DS} peak $< V_{(BR)DSS}$, $V_{DD} = 400 \text{ V}$.

3. $V_{DS} \le 480 V$.

Table 2. Thermal data

Symbol	I Parameter DPAK		Value			
Symbol			DPAK TO-220 IPAK		Unit	
R _{thj-case}	Thermal resistance junction-case		2.8			
R _{thj-pcb} ⁽¹⁾	Thermal resistance junction-pcb	50			°C/W	
R _{thj-amb}	Thermal resistance junction-ambient		62.5	100		

1. When mounted on 1 inch² FR-4, 2 Oz copper board.

Table 3. Avalanche characteristics

Symbol	Parameter	Value	Unit
I _{AR}	Avalanche current, repetitive or not repetitive ⁽¹⁾	0.5	А
E _{AS}	Single pulse avalanche energy ⁽²⁾	80	mJ

1. Pulse width limited by T_{jmax}

2. Starting $T_i = 25 \text{ °C}$, $I_D = I_{AR}$, $V_{DD} = 50 \text{ V}$



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	V_{GS} = 0 V, I _D = 1 mA	600			V
		V_{GS} = 0 V, V_{DS} = 600 V			1	
I _{DSS} Zer	Zero gate voltage drain current	V_{GS} = 0 V, V_{DS} = 600 V, T _C = 125 °C ⁽¹⁾			100	μA
I _{GSS}	Gate-body leakage current	V_{DS} = 0 V, V_{GS} = ±25 V			±10	μA
V _{GS(th)}	Gate threshold voltage	V_{DS} = V_{GS} , I_D = 250 μ A	2	3	4	V
R _{DS(on)}	Static drain-source on-resistance	V _{GS} = 10 V, I _D = 1.7 A		1.3	1.4	Ω

Table 4. On/off states

1. Defined by design, not subject to production test.

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance	$V_{1} = 100 V_{1} f = 1 M H_{7}$	-	211	-	
C _{oss}	Output capacitance	V _{DS} = 100 V, f = 1 MHz, V _{GS} = 0 V	-	13	-	pF
C _{rss}	Reverse transfer capacitance	VGS - 0 V	-	0.75	-	
Coss eq. ⁽¹⁾	Equivalent output capacitance	V_{DS} = 0 to 480 V, V_{GS} = 0 V	-	19.5	-	pF
R _G	Intrinsic gate resistance	f = 1 MHz open drain	-	6.2	-	Ω
Qg	Total gate charge	V _{DD} = 480 V, I _D = 3.5 A,	-	8	-	
Q _{gs}	Gate-source charge	V _{GS} = 0 to 10 V	-	1.6	-	nC
Q _{gd}	Gate-drain charge	(see Figure 16. Test circuit for gate charge behavior)	-	4.4	-	

1. C_{oss eq.} is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time	V _{DD} = 300 V, I _D = 1.7 A,	-	12	-	
t _r	Rise time	R _G = 4.7 Ω, V _{GS} = 10 V	-	3	-	
t _{d(off)}	Turn-off delay time	(see Figure 15. Test circuit for resistive load switching times and	-	70	-	ns
t _f	Fall time	Figure 20. Switching time waveform)	-	15	-	

Table 6. Switching times

Table	7.	Source-drain	diode

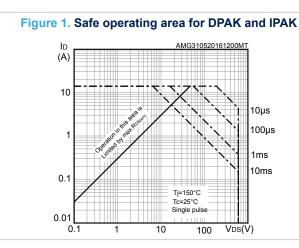
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current		-		3.5	А
I _{SDM} ⁽¹⁾	Source-drain current (pulsed)		-		14	А
V _{SD} ⁽²⁾	Forward on voltage	V _{GS} = 0 V, I _{SD} = 3.5 A	-		1.6	V
t _{rr}	Reverse recovery time	I _{SD} = 3.5 A, di/dt = 100 A/μs,	-	220		ns
Qrr	Reverse recovery charge	V _{DD} = 60 V	-	1.05		μC
I _{RRM}	Reverse recovery current	(see Figure 17. Test circuit for inductive load switching and diode recovery times)	-	9.5		A
t _{rr}	Reverse recovery time	I _{SD} = 3.5 A, di/dt = 100 A/μs,	-	314		ns
Q _{rr}	Reverse recovery charge	V _{DD} = 60 V, T _j = 150 °C	-	1.5		μC
I _{RRM}	Reverse recovery current	(see Figure 17. Test circuit for inductive load switching and diode recovery times)	-	9.5		A

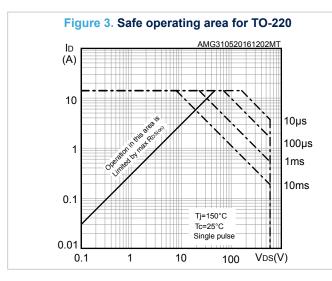
1. Pulse width is limited by safe operating area.

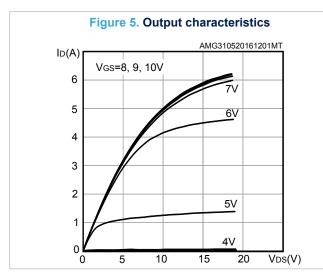
2. Pulse test: pulse duration = $300 \ \mu$ s, duty cycle 1.5 %.

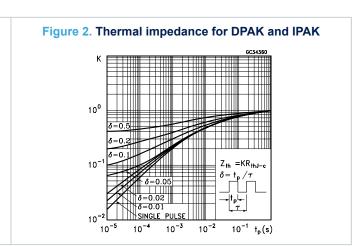


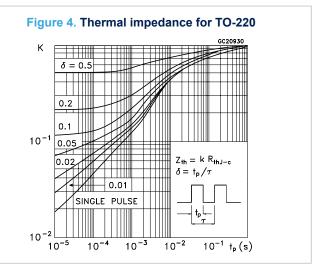
2.1 Electrical characteristics (curves)

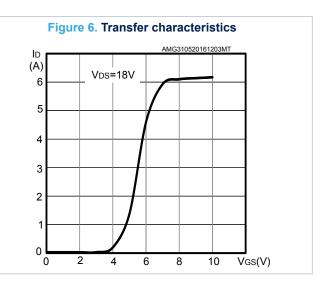




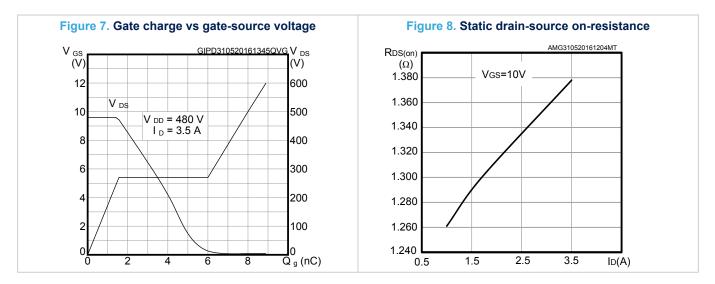


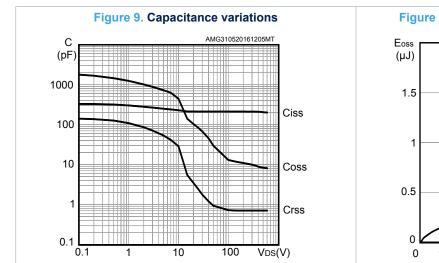


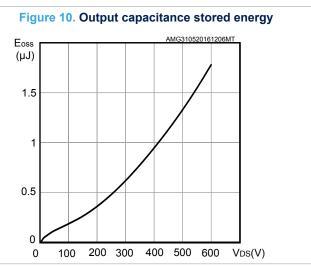












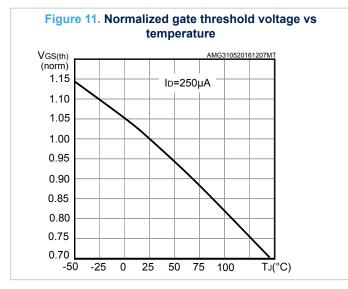
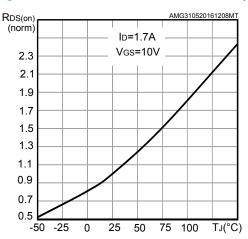
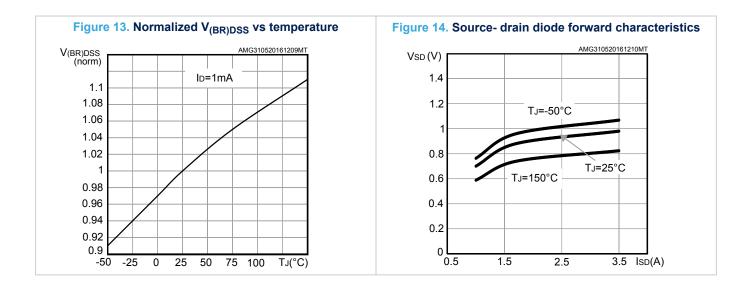


Figure 12. Normalized on-resistance vs temperature

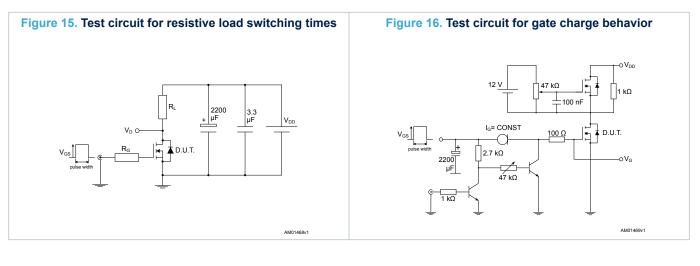


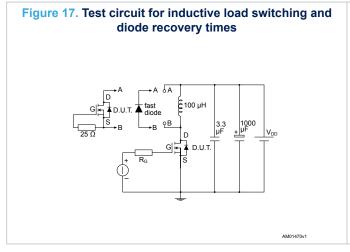


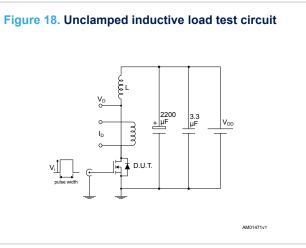


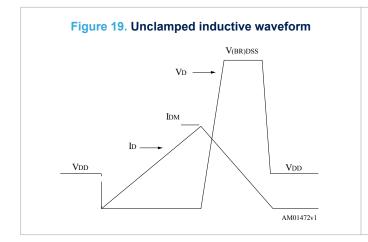


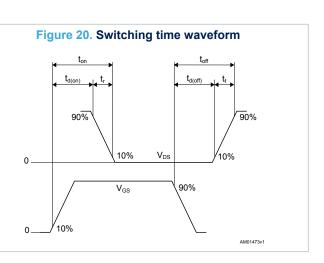
3 Test circuits













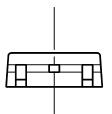
4 Package information

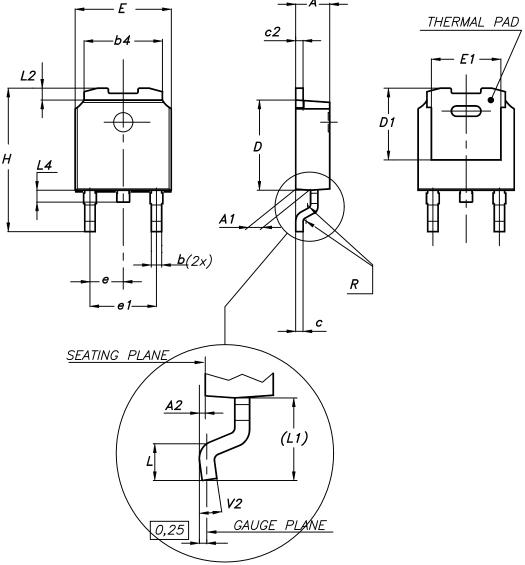
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4.1 DPAK (TO-252) type A2 package information

Figure 21. DPAK (TO-252) type A2 package outline





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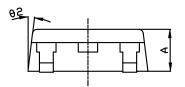
Dim.	mm				
Dim.	Min.	Тур.	Max.		
A	2.20		2.40		
A1	0.90		1.10		
A2	0.03		0.23		
b	0.64		0.90		
b4	5.20		5.40		
С	0.45		0.60		
c2	0.48		0.60		
D	6.00		6.20		
D1	4.95	5.10	5.25		
E	6.40		6.60		
E1	5.10	5.20	5.30		
e	2.159	2.286	2.413		
e1	4.445	4.572	4.699		
Н	9.35		10.10		
L	1.00		1.50		
L1	2.60	2.80	3.00		
L2	0.65	0.80	0.95		
L4	0.60		1.00		
R		0.20			
V2	0°		8°		

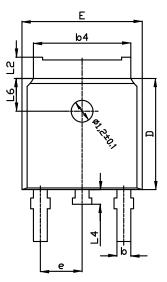
Table 8. DPAK (TO-252) type A2 mechanical data

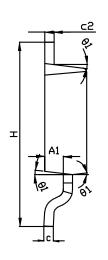


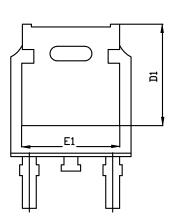
4.2 DPAK (TO-252) type C2 package information

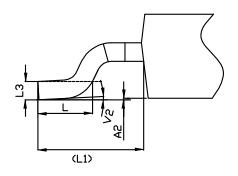
Figure 22. DPAK (TO-252) type C2 package outline











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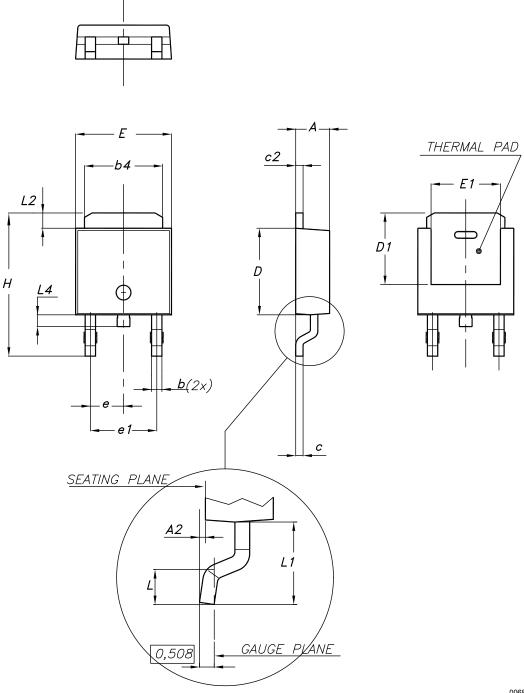
Dim.	mm			
Dim.	Min.	Тур.	Max.	
A	2.20	2.30	2.38	
A1	0.90	1.01	1.10	
A2	0.00		0.10	
b	0.72		0.85	
b4	5.13	5.33	5.46	
С	0.47		0.60	
c2	0.47		0.60	
D	6.00	6.10	6.20	
D1	5.10		5.60	
E	6.50	6.60	6.70	
E1	5.20		5.50	
e	2.186	2.286	2.386	
Н	9.80	10.10	10.40	
L	1.40	1.50	1.70	
L1		2.90 REF		
L2	0.90		1.25	
L3		0.51 BSC		
L4	0.60	0.80	1.00	
L6		1.80 BSC		
θ1	5°	7°	9°	
θ2	5°	7°	9°	
V2	0°		8°	

Table 9. DPAK (TO-252) type C2 mechanical data



4.3 DPAK (TO-252) type E package information

Figure 23. DPAK (TO-252) type E package outline

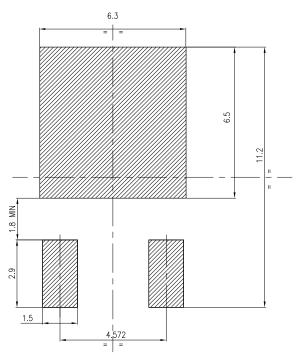


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Dim	mm		
	Min.	Тур.	Max.
A	2.18		2.39
A2			0.13
b	0.65		0.884
b4	4.95		5.46
С	0.46		0.61
c2	0.46		0.60
D	5.97		6.22
D1	5.21		
E	6.35		6.73
E1	4.32		
е		2.286	
e1		4.572	
Н	9.94		10.34
L	1.50		1.78
L1		2.74	
L2	0.89		1.27
L4			1.02

Table 10. DPAK (TO-252) type E mechanical data

Figure 24. DPAK (TO-252) recommended footprint (dimensions are in mm)

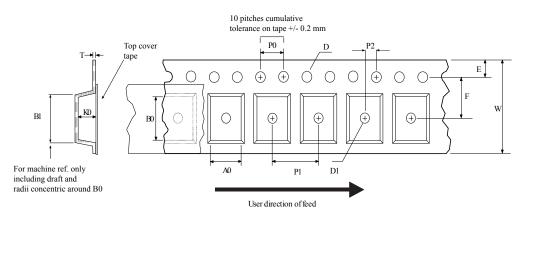


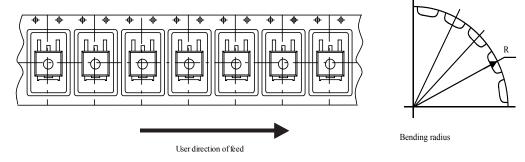
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4.4 DPAK (TO-252) packing information







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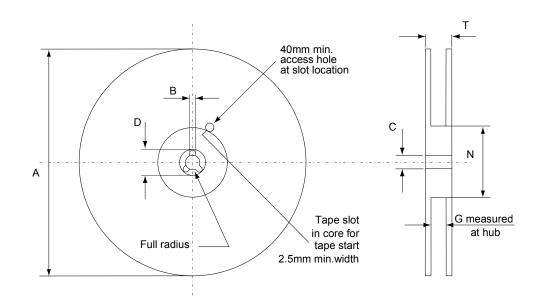


Figure 26. DPAK (TO-252) reel outline

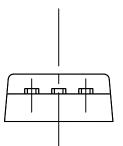
AM06038v1

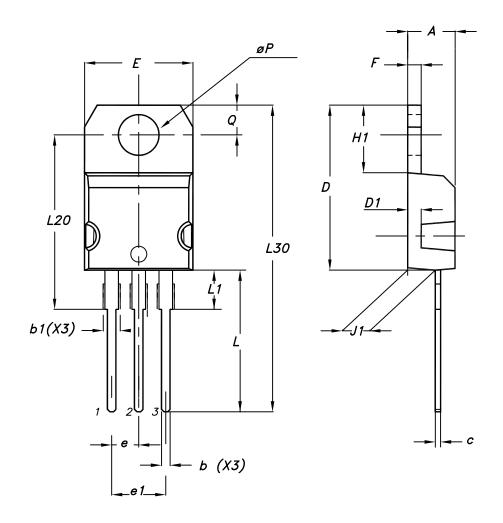
	Таре			Reel	
	n	mm		mm	
Dim.	Min.	Max.	– Dim.	Min.	Max.
A0	6.8	7	A		330
B0	10.4	10.6	В	1.5	
B1		12.1	С	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
E	1.65	1.85	N	50	
F	7.4	7.6	Т		22.4
K0	2.55	2.75			
P0	3.9	4.1	Bas	Base qty.	
P1	7.9	8.1	Bul	k qty.	2500
P2	1.9	2.1			
R	40				
Т	0.25	0.35			
W	15.7	16.3			



4.5 TO-220 type A package information

Figure 27. TO-220 type A package outline





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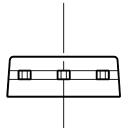
Dim.	mm			
	Min.	Тур.	Max.	
А	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.55	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10.00		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13.00		14.00	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
øP	3.75		3.85	
Q	2.65		2.95	

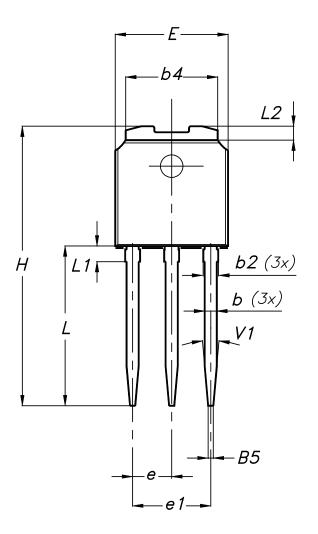
Table 12. TO-220 type A package mechanical data

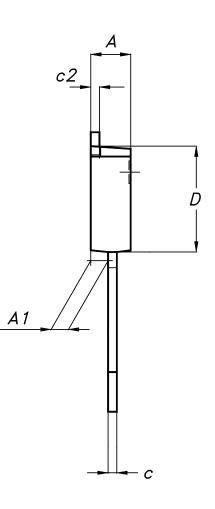


4.6 IPAK (TO-251) type A package information

Figure 28. IPAK (TO-251) type A package outline







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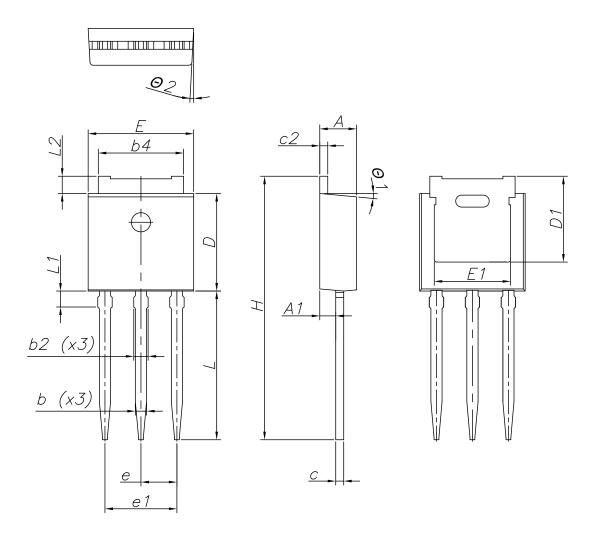
Dim.	mm			
	Min.	Тур.	Max.	
A	2.20		2.40	
A1	0.90		1.10	
b	0.64		0.90	
b2			0.95	
b4	5.20		5.40	
B5		0.30		
С	0.45		0.60	
c2	0.48		0.60	
D	6.00		6.20	
E	6.40		6.60	
e		2.28		
e1	4.40		4.60	
Н		16.10		
L	9.00		9.40	
L1	0.80		1.20	
L2		0.80	1.00	
V1		10°		

Table 13. IPAK (TO-251) type A package mechanical data



4.7 IPAK (TO-251) type C package information

Figure 29. IPAK (TO-251) type C package outline



0068771_IK_typeC_rev14

Dim.	mm			
	Min.	Тур.	Max.	
A	2.20	2.30	2.35	
A1	0.90	1.00	1.10	
b	0.66		0.79	
b2			0.90	
b4	5.23	5.33	5.43	
С	0.46		0.59	
c2	0.46		0.59	
D	6.00	6.10	6.20	
D1	5.20	5.37	5.55	
E	6.50	6.60	6.70	
E1	4.60	4.78	4.95	
e	2.20	2.25	2.30	
e1	4.40	4.50	4.60	
Н	16.18	16.48	16.78	
L	9.00	9.30	9.60	
L1	0.80	1.00	1.20	
L2	0.90	1.08	1.25	
θ1	3°	5°	7°	
θ2	1°	3°	5°	

Table 14. IPAK (TO-251) type C package mechanical data



5 Ordering information

Table 15. Ordering information

Order code	Marking	Package	Packing
STD5N60M2	5N60M2	DPAK	Tape and reel
STP5N60M2		TO-220	Tube
STU5N60M2		IPAK	Tube

Revision history

Table 16. Document revision history

Date	Revision	Changes
30-Sep-2013	1	First release.
20-Mar-2014	2	 Modified: ID, IDM and note 2 values in Table 2 Modified: the entire values in Table 4 Modified: RDS(on) typical and ID values in Table 5 Modified: the entire typical values, ISD and ISDM in Table 6, 7 and 8 Updated: Section 4.1: DPAK, STD5N60M2 Minor text changes
08-Jun-2016	3	Updated title, features, applications and description in cover page. Updated Section 1: "Electrical ratings", Table 6: "Dynamic" and Section 2.1: "Electrical characteristics (curves)". Updated IPAK C Minor text changes
16-Jun-2016	4	Updated Figure 1: "Internal schematic diagram". Updated Table 7: "Switching times" and Table 8: "Source-drain diode". Minor text changes.
01-Oct-2018	5	Updated Section 4 Package information. Minor text changes



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